



Package Style: QFN, 20-Pin, 3.5mmx3.5mmx0.5mm

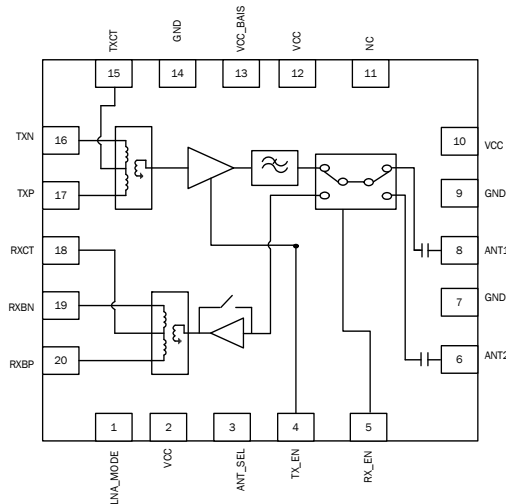


### Features

- TX Output Power: 22 dBm
- RX Gain: 11.5 dB
- RX NF: 2.5 dB
- Integrated RF Front End Module with TX/RX balun, PA, Filter, LNA with Bypass Mode and DP2T Switch.
- Dual Differential Transceiver Interface.

### Applications

- ZigBee® 802.15.4 Based Systems for Remote Monitoring and Control
- 2.4GHz ISM Band Applications
- Smart Meters for Energy Management



Functional Block Diagram

### Product Description

The RF6525 integrates a complete solution in a single Front End Module (FEM) for ZigBee® applications in the 2.4GHz to 2.5GHz band. This FEM integrates the PA plus harmonic filter in the transmit path and the LNA with bypass mode in the receive side. It also integrates a diversity switch and provides balanced input and output signals for both the TX and RX paths respectively.

The RF6525 FEM is ideal for ZigBee® systems operating with a minimum output power of 20dBm and high efficiency requirements. On the receive path, the RX Chain provides 11.5dB of typical gain with only 7 mA of current and excellent NF of 2.5dB. This FEM meets or exceeds the system requirements for ZigBee® applications operating in the 2.4GHz to 2.5GHz band. The device is provided in a 3.5mm x 3.5mm x 0.5mm, 20-pin QFN package.

### Ordering Information

|               |  |
|---------------|--|
| RF6525SQ      | Standard 25 piece bag                                |
| RF6525SR      | Standard 100 piece reel                              |
| RF6525TR13    | Standard 2500 piece reel                             |
| RF6525PCK-410 | Fully assembled evaluation board with 5 loose pieces |

### Optimum Technology Matching® Applied

- |   |                                      |  |                                    |
|---|--------------------------------------|--|------------------------------------|
| <input type="checkbox"/> GaAs HBT             | <input type="checkbox"/> SiGe BiCMOS | <input checked="" type="checkbox"/> GaAs pHEMT | <input type="checkbox"/> GaN HEMT  |
| <input type="checkbox"/> GaAs MESFET          | <input type="checkbox"/> Si BiCMOS   | <input type="checkbox"/> Si CMOS               | <input type="checkbox"/> BIFET HBT |
| <input checked="" type="checkbox"/> InGaP HBT | <input type="checkbox"/> SiGe HBT    | <input type="checkbox"/> Si BJT                | <input type="checkbox"/> LDMOS     |

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## Absolute Maximum Ratings

| Parameter   | Rating      | Unit |
|---|-------------|------|
| DC Supply Voltage   | 5           | V    |
| Operating Case Temperature                                      | -40 to +85  | °C   |
| Storage Temperature   | -40 to +150 | °C   |
| ESD Human Body Model RF Pins                                    | 1000        | V    |
| ESD Human Body Model All Other Pins                             | 500         | V    |
| ESD Charge Device Model All Pins                                | 500         | V    |
| Moisture Sensitivity Level                                      | MSL 2       |      |
| Maximum Input Power to PA and LNA (No Damage in High Gain Mode) | +5          | dBm  |



**Caution!** ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

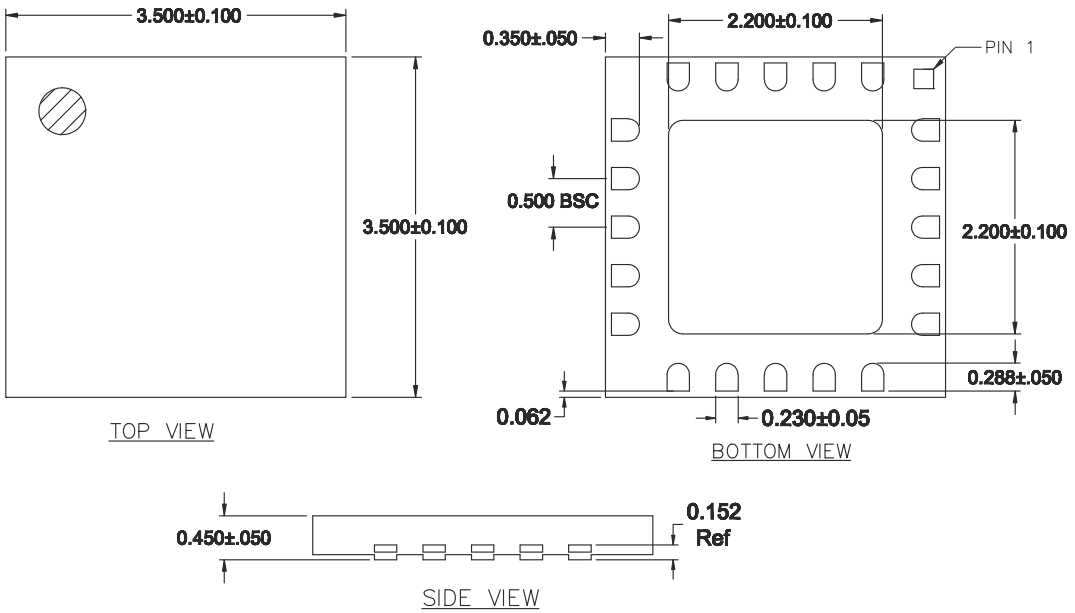
| Parameter                                       | Specification |      |      | Unit    | Condition  |
|---|---------------|------|------|---------|--|
|   | Min.          | Typ. | Max. |         |  |
| <b>Overall</b>                                  |               |      |      |         | Specifications must be met across supply voltage, control voltage, and temperature ranges unless otherwise noted. Typical conditions: T=25 °C, V <sub>CC</sub> =3.6V, TX_EN=High |
| Operating Frequency Range                       | 2400          |      | 2483 | MHz     |  |
| Operating Voltage (V <sub>CC</sub> )            | 3.0           | 3.6  | 4.2  | V       |  |
| Leakage Current                                 |               | 0.5  |      | uA      | V <sub>CC</sub> =3.6V, RF=OFF, TX_EN=Low, RX_EN=Low. LNA_EN, ANT_SEL, and LNA Mode=Low.  |
| <b>Transmit Parameters</b>                      |               |      |      |         |  |
| Frequency                                       | 2400          |      | 2483 | MHz     |  |
| Input Return Loss                               |               | -13  | -9.6 | dB      | Over all conditions for both Antenna 1 and Antenna 2   |
| Amplitude Imbalance                             | -1            |      | 1    | dB      |  |
| Phase Imbalance                                 | -15           |      | 15   | deg     |  |
| Output Return Loss                              |               | -14  | -9.6 | dB      | Over all conditions for both Antenna 1 and Antenna 2   |
| Gain  | 25            | 28   |      | dB      | At rated power and nominal conditions  |
| Gain Variation                                  | -1.5          |      | +1.5 | dB      | Over temperature   |
| Gain Flatness                                   | -1            |      | +1   | dB      | Over frequencies and voltage   |
| Rated Output Power                              | 20            | 22   |      | dBm     |  |
|   |               | 19   |      | dBm     | V <sub>CC</sub> =2.6V, V <sub>CC-Bias</sub> =3.0V  |
| Supply Current                                  |               | 200  | 230  | mA      | P <sub>O</sub> =22dBm 802.15.4 OQPSK. Typical Conditions.  |
| Supply Current                                  |               | 175  | 205  | mA      | P <sub>O</sub> =20dBm 802.15.4 OQPSK.  |
| Thermal Resistance                              |               | 53   |      | °C/W    | V <sub>CC</sub> = 3.6V, P <sub>OUT</sub> = 22dBm, T <sub>REF</sub> = 85 °C   |
| 2nd Harmonic Level                              |               | -45  | -42  | dBm/MHz | Measured using standard 802.15.4 OQPSK modulation signal at P <sub>OUT</sub> =20dBm over temperature, frequency, and voltage   |
| 3rd Harmonic Level                              |               | -45  | -42  | dBm/MHz | Measured using standard 802.15.4 OQPSK modulation signal at P <sub>OUT</sub> =20dBm over temperature, frequency, and voltage   |
| VSWR Stability and Load Mismatch Susceptibility | 4:1           |      |      |         | No spurs above -45dBm  |
| VSWR No Damage                                  | 8:1           |      |      |         |  |

| Parameter                             | Specification         |      |                  | Unit | Condition  |
|---------------------------------------|-----------------------|------|------------------|------|--|
|                                       | Min.                  | Typ. | Max.             |      |  |
| <b>Transmit Parameters, cont.</b>     |                       |      |                  |      |  |
| Gain Settling Time                    |                       | 1    | 2                | µS   |  |
| Current Sourced through TXCT Pin      |                       |      | 18.0             | mA   |  |
| Voltage Drop from TXCT Pin to TXP/TXN |                       |      | 0.1              | V    |  |
| <b>Receive Parameters (LNA Mode)</b>  |                       |      |                  |      |  |
| Frequency                             | 2400                  |      | 2483             | MHz  |  |
| Gain                                  | 8                     | 11.5 | 14               | dB   | From antenna to RX pin (entire RX path). (All conditions.)   |
| Noise Figure                          |                       | 2.5  | 3.5              | dB   | From antenna to RX pin (entire RX path).   |
| Current                               |                       | 8    | 12               | mA   | LNA + Switches   |
| Input IP3                             | 5                     | 10   |                  | dBm  | At nominal conditions  |
| Gain Flatness                         | -0.7                  |      | 0.7              | dB   | over frequency   |
| Input Return Loss                     |                       | 10   |                  | dB   |  |
| Output Return Loss                    |                       |      | 8                | dB   |  |
| Amplitude Imbalance                   | -1                    |      | 1                | dB   | Differential RX Port   |
| Phase Imbalance                       | -15                   |      | 15               | deg  | On 180 degrees typical, differential RX Port   |
| Current Sourced through RXCT Pin      |                       |      | 1                | mA   |  |
| Voltage Drop from RXCT Pin to RXP/RXN |                       | 0.05 | 0.1              | V    |  |
| <b>ByPass Mode</b>                    |                       |      |                  |      |  |
| Frequency                             | 2400                  |      | 2483             | MHz  |  |
| Insertion Loss                        |                       | 5    | 7                | dB   | Entire RX path   |
| Noise Figure                          |                       | 5    |                  | dB   | Entire RX path   |
| Current                               |                       | 5    |                  | µA   | ANT1   |
|                                       |                       | 50   |                  | µA   | ANT2   |
| IIP3                                  |                       | 18   |                  | dBm  | Nominal  |
| Gain Flatness                         | -0.1                  |      | 0.1              | dB   | over frequency   |
| Input Return Loss                     |                       | 15   | 12               | dB   |  |
| Output Return Loss                    |                       | 9.5  | 8                | dB   |  |
| Amplitude Imbalance                   | -1                    |      | 1                | dB   | Differential RX Port   |
| Phase Imbalance                       | -15                   |      | 15               | deg  | On 180 degrees typical, differential RX Port   |
| Current Sourced through RXCT Pin      |                       |      | 1                | mA   |  |
| Voltage Drop from RXCT Pin to RXP/RXN |                       | 0.05 | 0.1              | V    |  |
| <b>Antenna Switch</b>                 |                       |      |                  |      |  |
| RF-to-Control Isolation               |                       | 50   |                  | dB   | Measured at any control pin while in TX or RX mode.  |
| RF-to-ANT Isolation                   | 17                    | 20   |                  | dB   | Measured from Antenna to RX port while in Transmit mode. Measured from Antenna to TX port while in Receive mode. |
| RF-to-RF Isolation                    | 18                    | 20   |                  | dB   | Measured from TX port to RX port while in receive or transmit modes.   |
| Switch Control Logic = HIGH           | =V <sub>CC</sub> -0.3 |      | =V <sub>CC</sub> | V    | All Logic I/O's  |
| Switch Control Logic = LOW            | 0.0                   |      | 0.2              | V    | All Logic I/O's  |

|                                    |  |     |   |               |                                  |
|------------------------------------|--|-----|---|---------------|----------------------------------|
| Switch Control Current. Logic HIGH |  | 2   | 5 | $\mu\text{A}$ | All Logic I/O's                  |
| Switch Control Current. Logic LOW  |  | 0.1 |   | $\mu\text{A}$ | All Logic I/O's                  |
| Antenna Select Switch Speed        |  |     | 1 | $\mu\text{S}$ | ANT1 or ANT2 path, TX or RX mode |

| Pin | Function | Description  |
|-----|----------|--|
| 1   | LNA_MODE | Bypass enable pin. See logic table for operation.  |
| 2   | VCC      | Voltage Supply. An external 1uF capacitor might be needed for low frequency decoupling.      |
| 3   | ANT_SEL  | Control pin for Antenna select. See logic table for operation.                               |
| 4   | TX_EN    | Enable voltage pin for the PA and Transmit switch. See logic table for operation.            |
| 5   | RX_EN    | Enable voltage pin for the LNA and Receive switch. See logic table for operation             |
| 6   | ANT2     | This is the common port (antenna). It is matched to 50Ω and DC-block is provided internally. |
| 7   | GND      | Ground.  |
| 8   | ANT1     | This is the common port (antenna). It is matched to 50Ω and DC-block is provided internally  |
| 9   | GND      | Ground.  |
| 10  | VCC      | Voltage Supply. An external 1uF capacitor might be needed for low frequency decoupling       |
| 11  | NC       | No connect pin. Must be left floating.   |
| 12  | VCC      | Voltage Supply. An external 1uF capacitor might be needed for low frequency decoupling       |
| 13  | VCC_BIAS | Voltage Supply. An external 1uF capacitor might be needed for low frequency decoupling       |
| 14  | GND      | Ground.  |
| 15  | TXCT     | Center tap for passing thru DC voltage to TXN and TXP pins that connect to the TXVR SolC.    |
| 16  | TXN      | 100Ω single-ended, 200Ω differential.  |
| 17  | TXP      | 100Ω single-ended, 200Ω differential.  |
| 18  | RXCT     | Center tap for passing thru DC voltage to RXBN and RXBP pins that connect to the TXVR SolC.  |
| 19  | RXBN     | 100Ω single-ended, 200Ω differential.  |
| 20  | RXBP     | 100Ω single-ended, 200Ω differential.  |

## Package Drawing



## RF6525 Biasing Instructions

### TX Mode

- With the RF source disabled, apply 3.3V to  $V_{CC}$  with other control set to 0V
- Set VTX=High, keeping VRX and LNA\_MODE at 0V
- Apply 0V to ANT\_SEL to select the ANT1 port, or 2.8V to select the ANT2 port
- $V_{CC}$  current should rise to 70mA to 80mA quiescent current
- Enable the RF source;  $V_{CC}$  current should rise to a maximum of 200mA depending on output power

### RX LNA Mode

- With the RF source disabled, apply 3.3V to  $V_{CC}$  with other controls set to 0V
- Set VRX=High to RX Enable and LNA\_MODE, keeping TX at 0V
- Apply 0V to ANT\_SEL to select the ANT1 port, or 2.8V to select the ANT2 port
- $V_{CC}$  current should rise to 7 mA to 8mA
- Enable the RF source;  $V_{CC}$  current may increase a few mA depending on output power

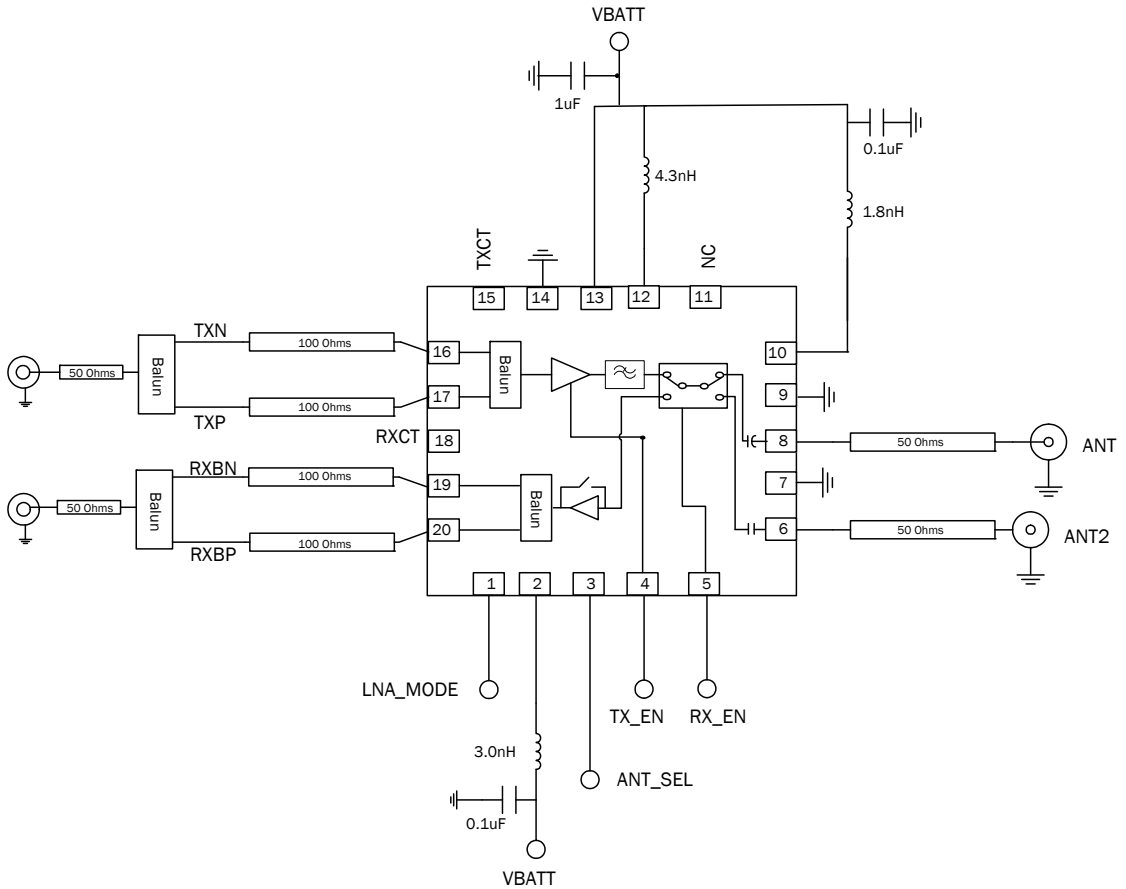
### RX Bypass Mode

- With the RF source disabled, apply 3.3V to  $V_{CC}$  with other controls set to 0V
- Set VRX=High, keeping TX and LNA\_MODE at 0V
- Apply 0V to ANT\_SEL to select the ANT1 port, or 2.8V to select the ANT2 port
- $V_{CC}$  current should be in the uA range
- Enable the RF source;  $V_{CC}$  current should remain in the uA range

| Logic Table |       |       |          |         |
|-------------|-------|-------|----------|---------|
| Mode        | TX_EN | RX_EN | LNA_MODE | ANT_SEL |
| TX-ANT1     | HIGH  | LOW   | LOW      | LOW     |
| TX_ANT2     | HIGH  | LOW   | LOW      | HIGH    |
| RX-ANT1 LNA | LOW   | HIGH  | HIGH     | LOW     |
| RX-ANT1 BYP | LOW   | HIGH  | LOW      | LOW     |
| RX-ANT2LNA  | LOW   | HIGH  | HIGH     | HIGH    |
| RX-ANT2 BYP | LOW   | HIGH  | LOW      | HIGH    |
| All OFF     | LOW   | LOW   | LOW      | LOW     |

Operating currents at nominal conditions

## Evaluation Board Schematic





## PCB Design Requirements

### PCB Surface Finish

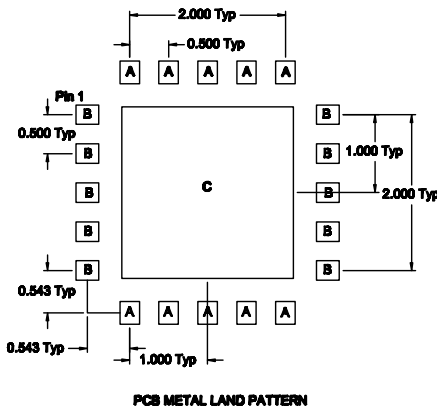
The PCB surface finish used for RFMD's qualification process is electroless nickel, immersion gold. Typical thickness is 3µinch to 8µinch gold over 180µinch nickel.

### PCB Land Pattern Recommendation

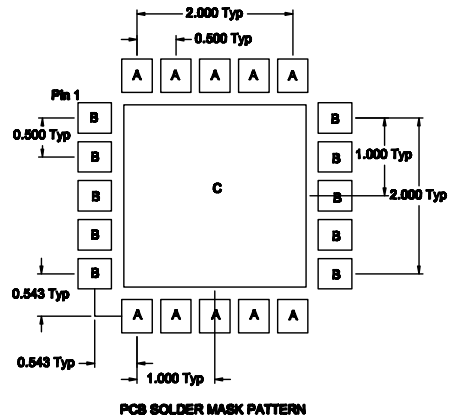
PCB land patterns for RFMD components are based on IPC-7351 standards and RFMD empirical data. The pad pattern shown has been developed and tested for optimized assembly at RFMD. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.

### PCB Metal Land and Solder Mask Pattern

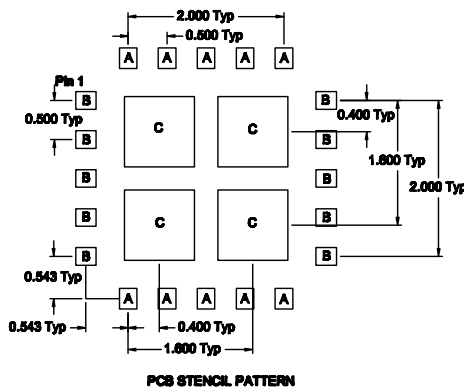
A = 0.290 x 0.290 (mm) Typ Rounded Rectangle 60%  
 B = 0.290 x 0.290 (mm) Typ Rounded Rectangle 50%  
 C = 2.200 (mm) Sq Rounded Rectangle 5%



A = 0.360 x 0.430 (mm) Typ Rounded Rectangle 60%  
 B = 0.430 x 0.360 (mm) Typ Rounded Rectangle 50%  
 C = 2.340 (mm) Sq Rounded Rectangle 5%



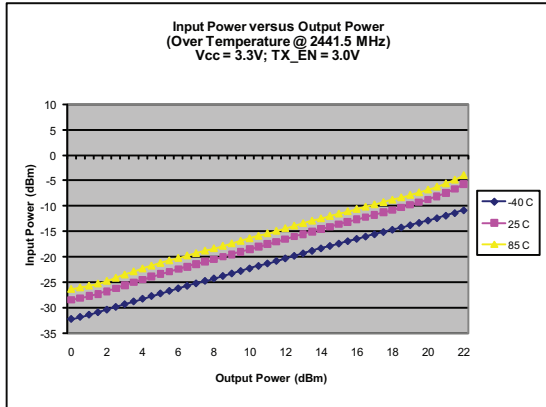
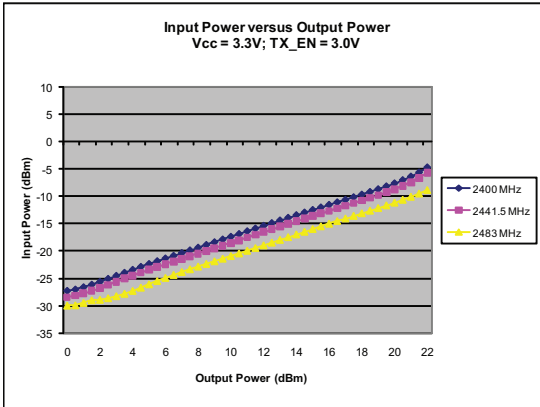
A = 0.225 x 0.261 (mm) Typ Rounded Rectangle 10%  
 B = 0.261 x 0.225 (mm) Typ Rounded Rectangle 10%  
 C = 0.900 (mm) Sq Typ Rounded Rectangle 10%



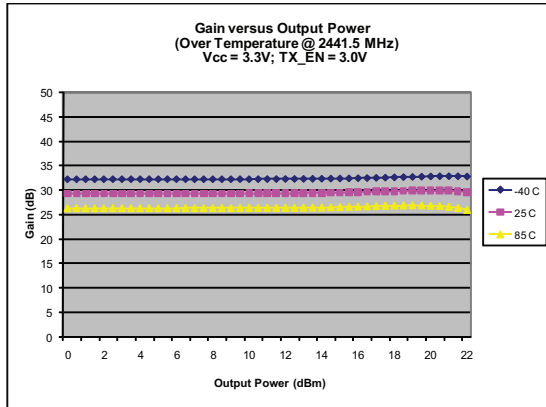
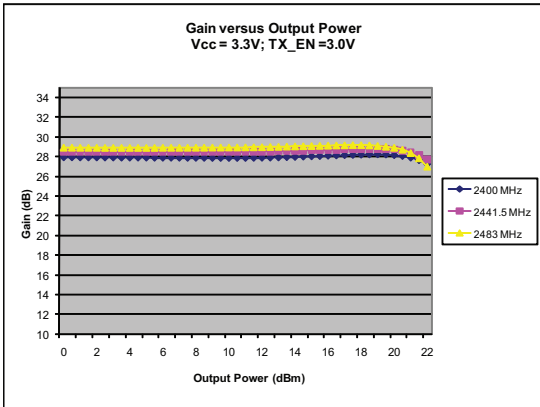
Thermal vias for center slug "C" should be incorporated into the PCB design. The number and size of thermal vias will depend on the application, the power dissipation, and this electrical requirements. Example of the number and size of vias can be found on the RFMD evaluation board layout.

## RF6525 2.4 GHz Front End Module

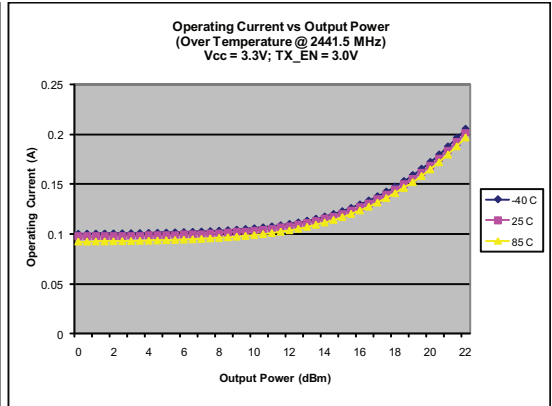
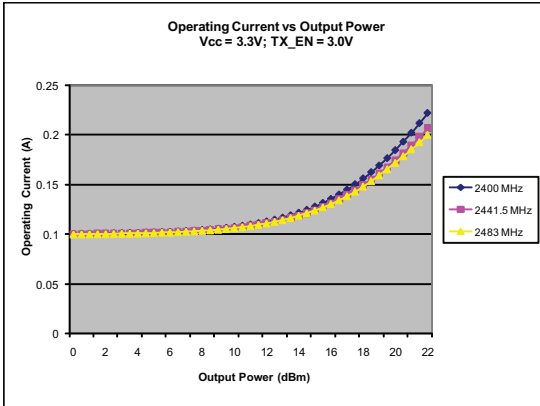
### Input Power versus Output Power



### Gain versus Output Power



**RF6525 2.4 GHz Front End Module**  
 Operating Current versus Output Power



**TX S21 versus Frequency**

